

# 2SB1202/2SD1802

## ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

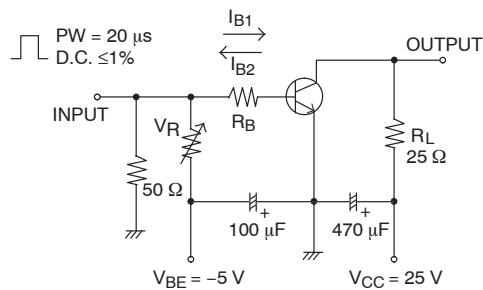
| Parameter                               | Symbol        | Conditions                                         | Ratings |               |             | Unit          |
|-----------------------------------------|---------------|----------------------------------------------------|---------|---------------|-------------|---------------|
|                                         |               |                                                    | Min     | Typ           | Max         |               |
| Collector Cutoff Current                | $I_{CBO}$     | $V_{CB} = (-)40\text{ V}, I_E = 0\text{ A}$        |         |               | $(-)1$      | $\mu\text{A}$ |
| Emitter Cutoff Current                  | $I_{EBO}$     | $V_{EB} = (-)4\text{ V}, I_C = 0\text{ A}$         |         |               | $(-)1$      | $\mu\text{A}$ |
| DC Current Gain                         | $h_{FE1}$     | $V_{CE} = (-)2\text{ V}, I_C = (-)100\text{ mA}$   | 100*    |               | 560*        |               |
|                                         | $h_{FE2}$     | $V_{CE} = (-)2\text{ V}, I_C = (-)3\text{ A}$      | 35      |               |             |               |
| Gain-Bandwidth Product                  | $f_T$         | $V_{CE} = (-)10\text{ V}, I_C = (-)50\text{ mA}$   |         | 150           |             | MHz           |
| Output Capacitance                      | $C_{ob}$      | $V_{CB} = (-)10\text{ V}, f = 1\text{ MHz}$        |         | (39)25        |             | pF            |
| Collector to Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C = (-)2\text{ A}, I_B = (-)100\text{ mA}$      |         | $(-0.35)0.19$ | $(-0.7)0.5$ | V             |
| Base to Emitter Saturation Voltage      | $V_{BE(sat)}$ | $V_{CE} = (-)2\text{ V}, I_C = (-)100\text{ mA}$   |         | $(-)0.94$     | $(-)1.2$    | V             |
| Collector to Base Breakdown Voltage     | $V_{(BR)CBO}$ | $I_C = (-)10\text{ }\mu\text{A}, I_E = 0\text{ A}$ | $(-)60$ |               |             | V             |
| Collector to Emitter Breakdown Voltage  | $V_{(BR)CEO}$ | $I_C = (-)1\text{ mA}, R_{BE} = \Omega$            | $(-)50$ |               |             | V             |
| Emitter to Base Breakdown Voltage       | $V_{(BR)EBO}$ | $I_E = (-)10\text{ }\mu\text{A}, I_C = 0\text{ A}$ | $(-)6$  |               |             | V             |
| Turn-On Time                            | $t_{on}$      | See specified Test Circuit                         |         | 70            |             | ns            |
| Storage Time                            | $t_{stg}$     |                                                    |         | (450)650      |             | ns            |
| Fall Time                               | $t_f$         |                                                    |         | 35            |             | ns            |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

\*The 2SB1202/2SD1802 are classified by 100 mA  $h_{FE}$  as follows :

| Rank     | R          | S          | T          | U          |
|----------|------------|------------|------------|------------|
| $h_{FE}$ | 100 to 200 | 140 to 280 | 200 to 400 | 280 to 560 |

## Switching Time Test Circuit



$I_C = 10\text{ A}, I_{B1} = -10\text{ A}, I_{B2} = 1\text{ A}$   
For PNP, the polarity is reversed.

TYPICAL CHARACTERISTICS

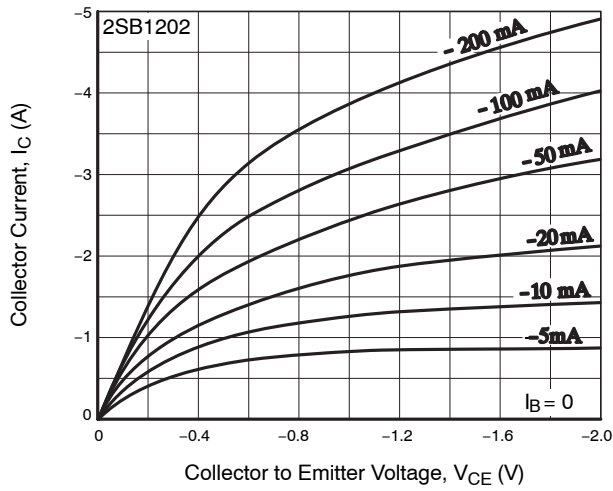


Figure 1.  $I_C - V_{CE}$

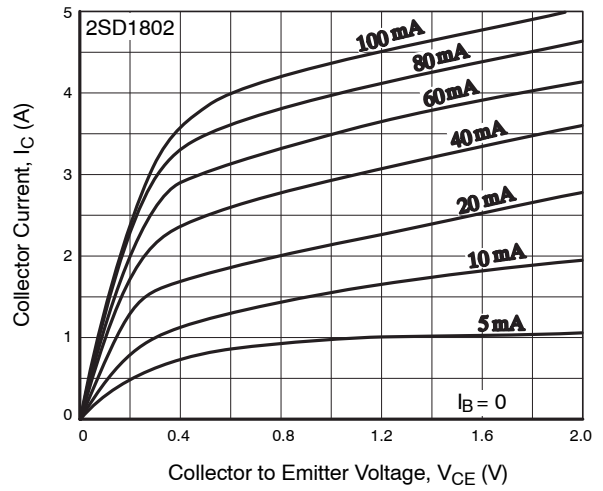


Figure 2.  $I_C - V_{CE}$

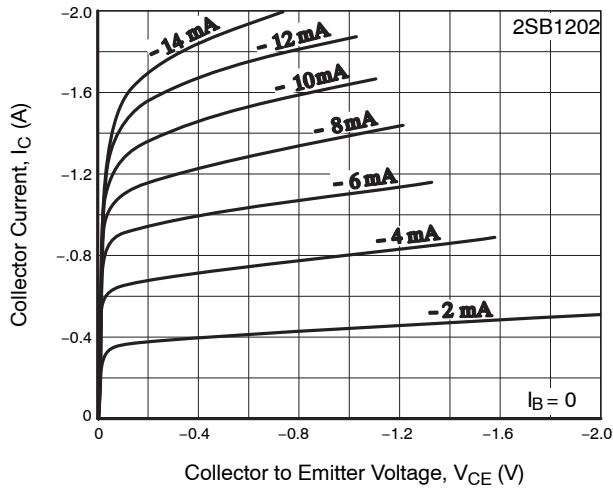


Figure 3.  $I_C - V_{CE}$

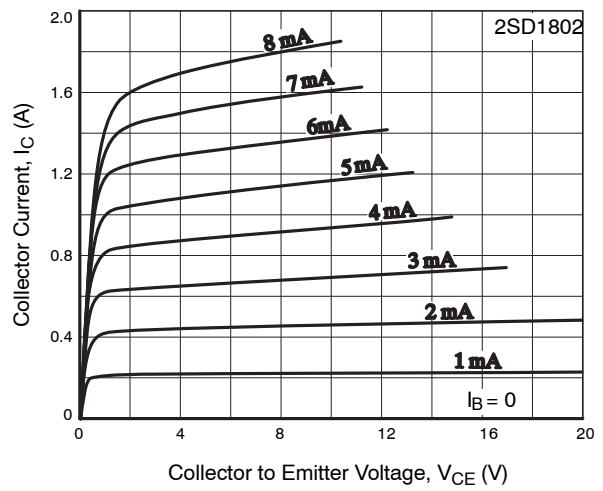


Figure 4.  $I_C - V_{CE}$

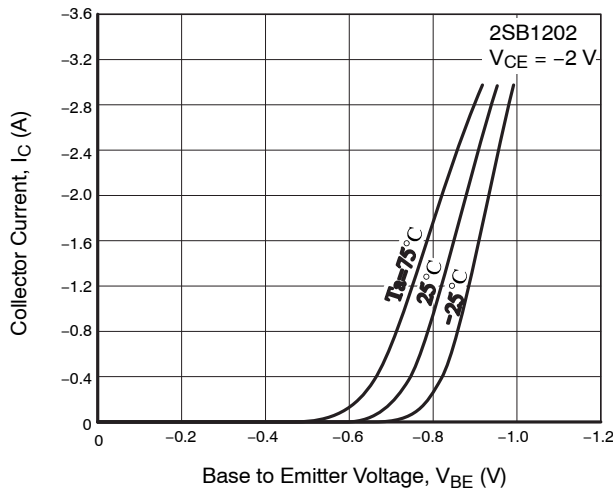


Figure 5.  $I_C - V_{BE}$

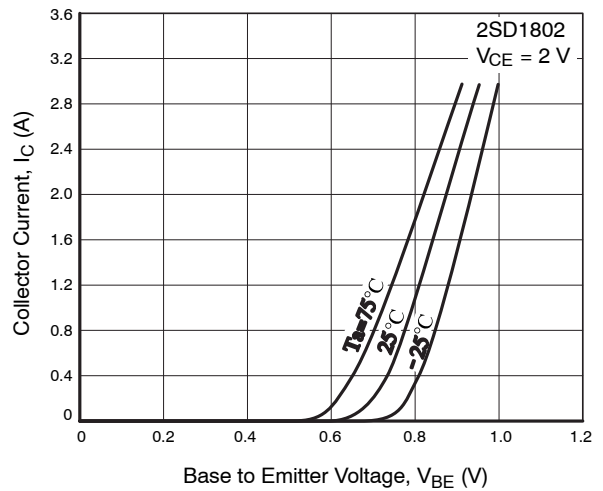


Figure 6.  $I_C - V_{BE}$

TYPICAL CHARACTERISTICS (continued)

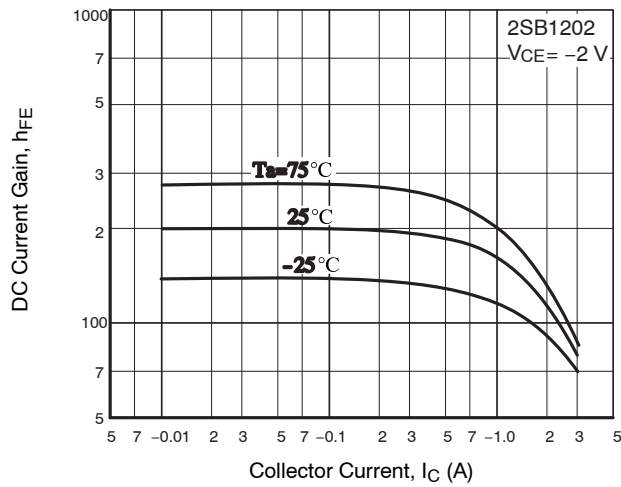


Figure 7.  $h_{FE} - I_C$

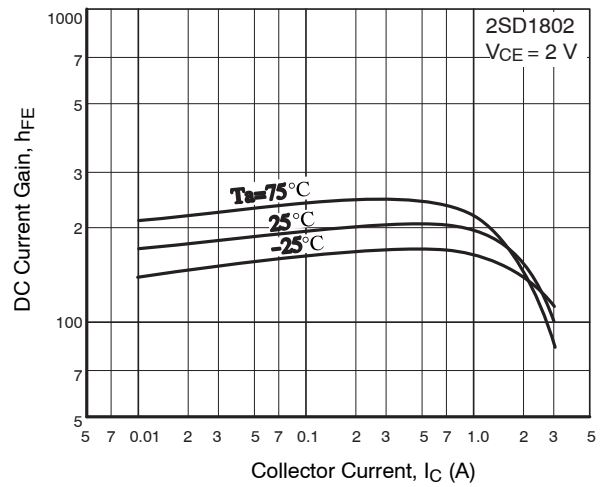


Figure 8.  $h_{FE} - I_C$

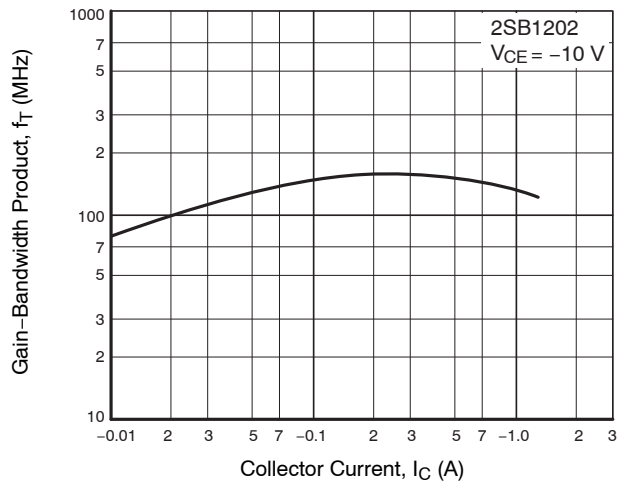


Figure 9.  $f_T - I_C$

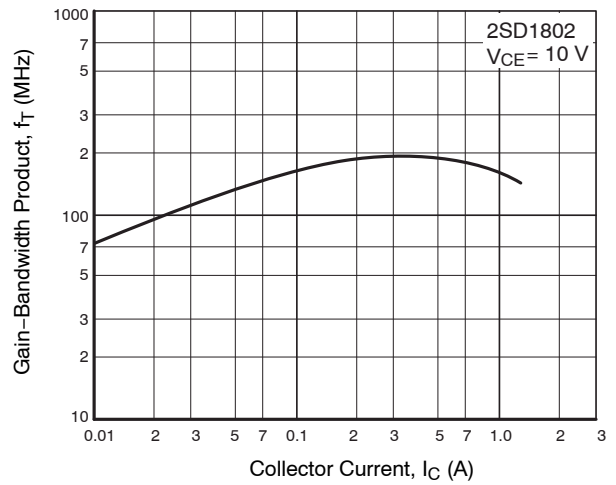


Figure 10.  $f_T - I_C$

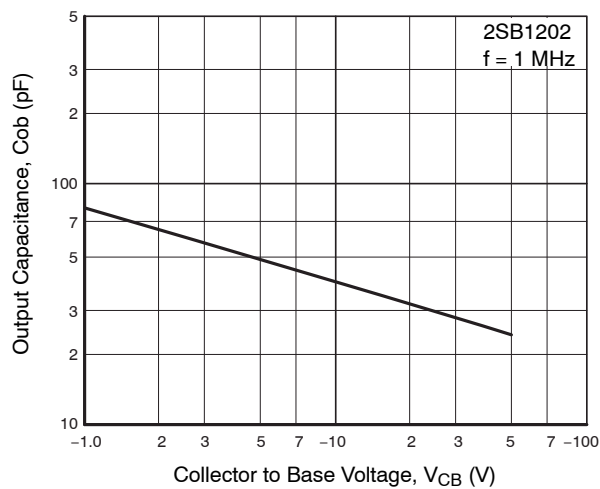


Figure 11.  $C_{ob} - V_{CB}$

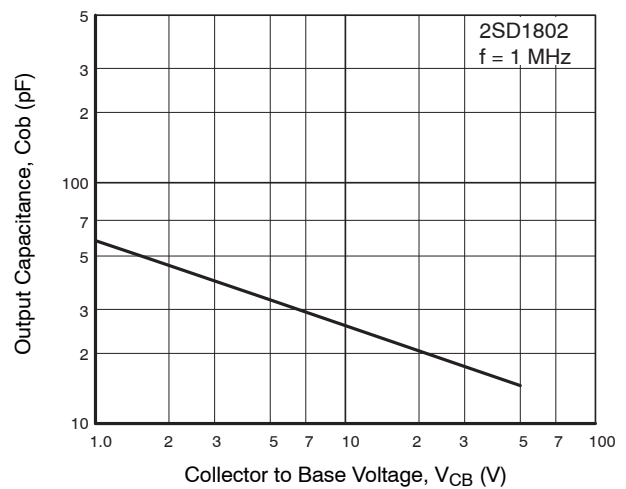


Figure 12.  $C_{ob} - V_{CB}$

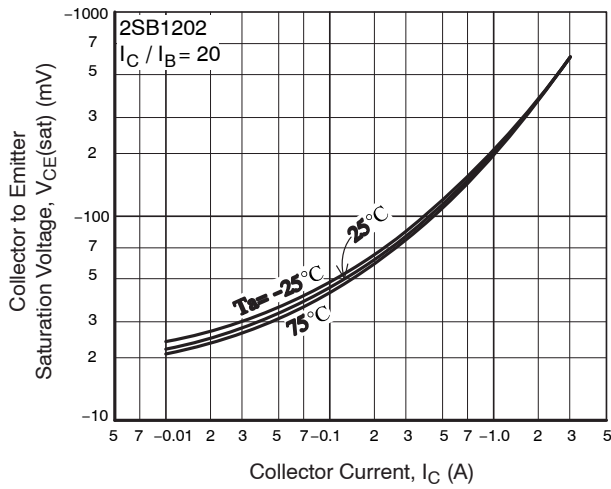


Figure 13.  $V_{CE(sat)} - I_C$

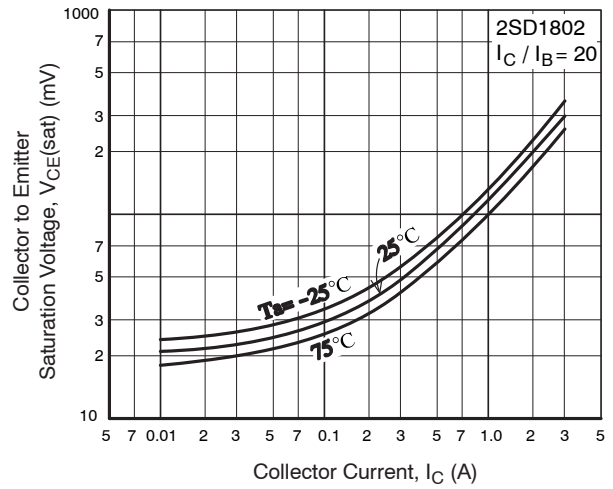


Figure 14.  $V_{CE(sat)} - I_C$

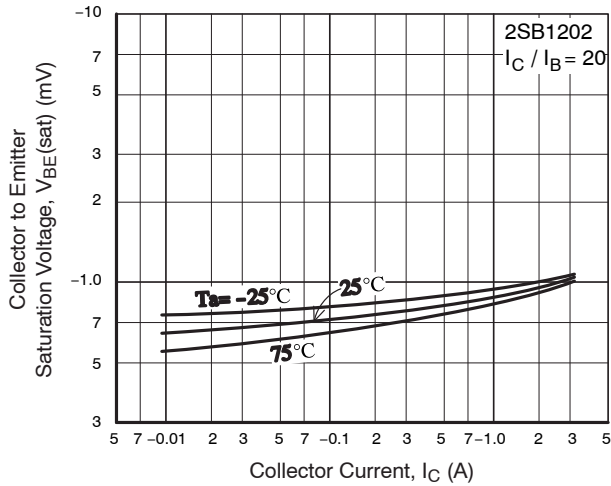


Figure 15.  $V_{BE(sat)} - I_C$

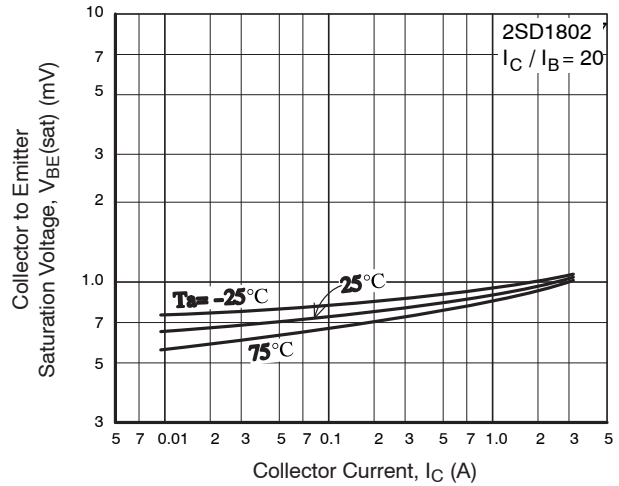


Figure 16.  $V_{BE(sat)} - I_C$

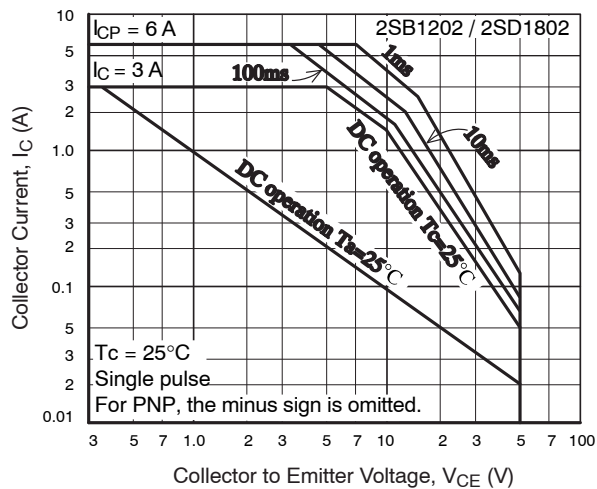


Figure 17. ASO

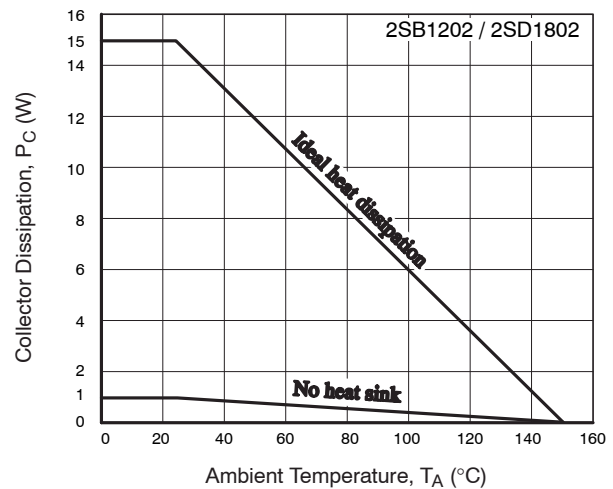


Figure 18.  $P_C - T_A$

## 2SB1202/2SD1802

### ORDERING INFORMATION

| Device        | Package | Shipping†    | memo    |
|---------------|---------|--------------|---------|
| 2SB1202S-E    | TP      | 500pcs./bag  | Pb-Free |
| 2SB1202T-E    | TP      | 500pcs./bag  |         |
| 2SD1802S-E    | TP      | 500pcs./bag  |         |
| 2SD1802T-E    | TP      | 500pcs./bag  |         |
| 2SB1202S-TL-E | TP-FA   | 700pcs./reel |         |
| 2SB1202T-TL-E | TP-FA   | 700pcs./reel |         |
| 2SD1802S-TL-E | TP-FA   | 700pcs./reel |         |
| 2SD1802T-TL-E | TP-FA   | 700pcs./reel |         |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MECHANICAL CASE OUTLINE

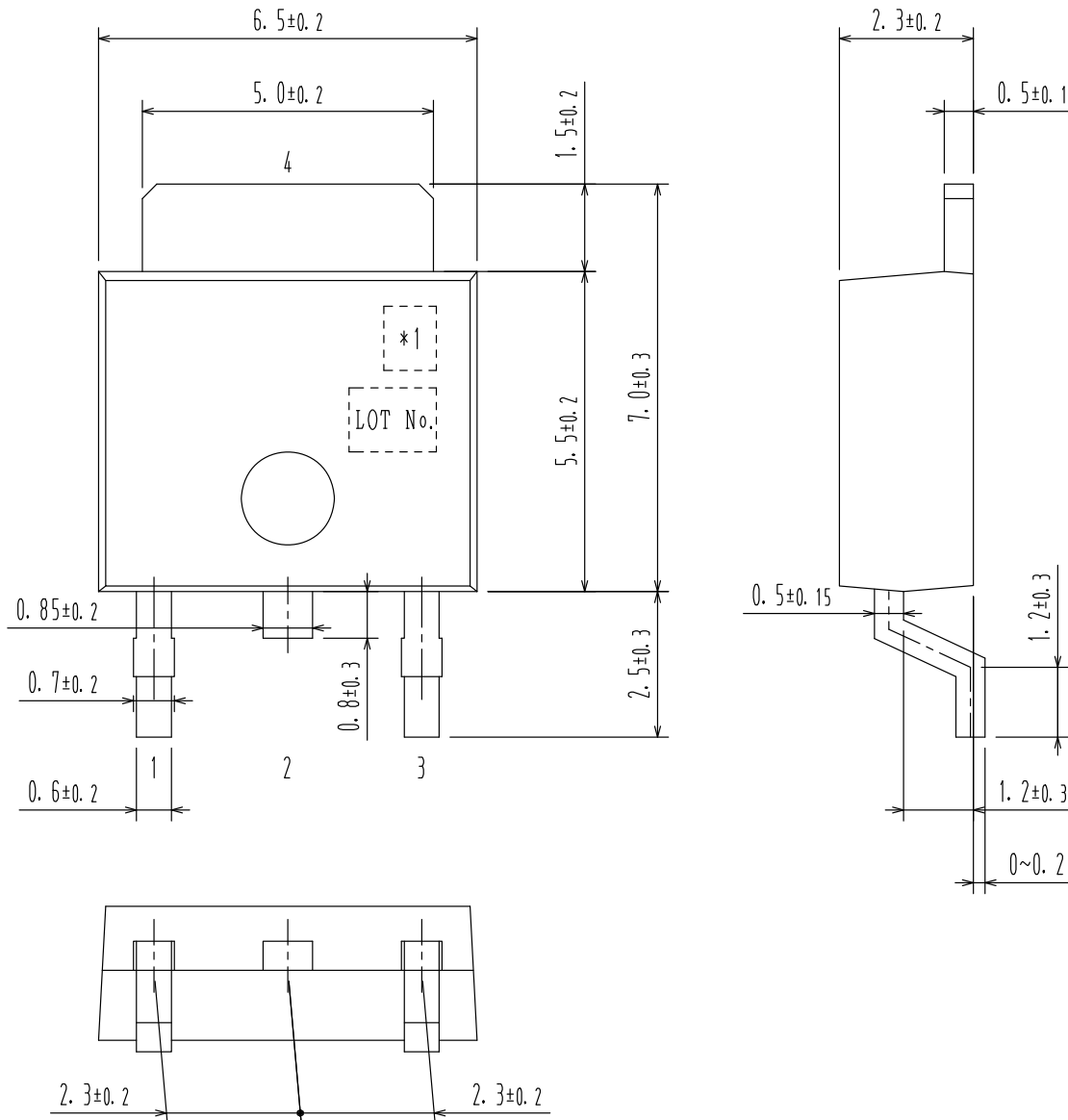
## PACKAGE DIMENSIONS

ON Semiconductor®

ON

DPAK / TP-FA  
CASE 369AH  
ISSUE O

DATE 30 JAN 2012



Pin 2 is idle pin with electrical designation only carried.

1:  
2:  
3:  
\*1: Lot indication 4:

|                  |              |                                                                                                                                                                                  |
|------------------|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DOCUMENT NUMBER: | 98AON66236E  | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION:     | DPAK / TP-FA | PAGE 1 OF 1                                                                                                                                                                      |

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

# MECHANICAL CASE OUTLINE

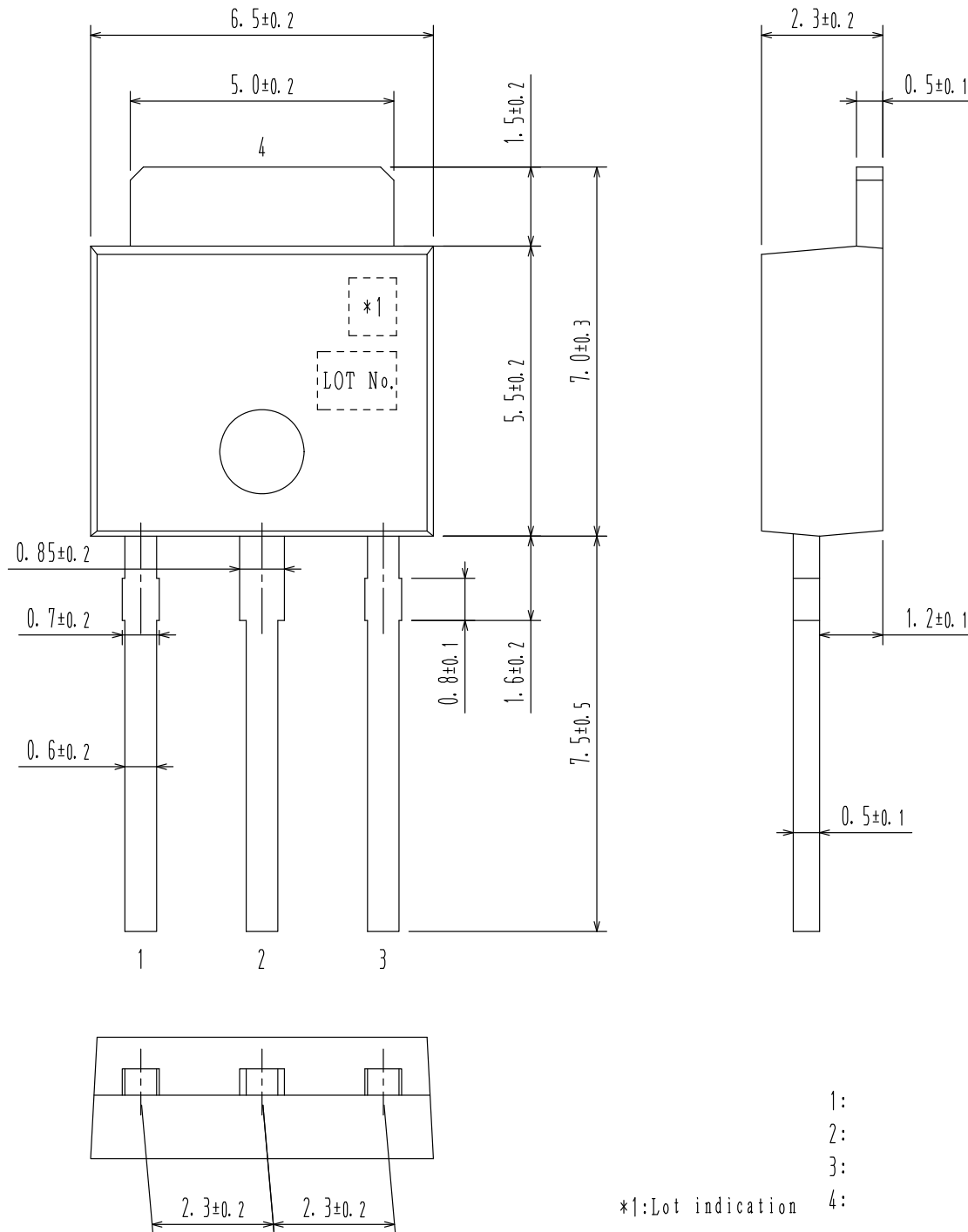
## PACKAGE DIMENSIONS

ON Semiconductor®

ON

IPAK / TP  
CASE 369AJ  
ISSUE O

DATE 30 JAN 2012



|                  |             |                                                                                                                                                                                     |
|------------------|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DOCUMENT NUMBER: | 98AON66237E | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION:     | IPAK / TP   | PAGE 1 OF 1                                                                                                                                                                         |

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Email Requests to: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**onsemi Website:** [www.onsemi.com](http://www.onsemi.com)

### TECHNICAL SUPPORT

**North American Technical Support:**

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

**Europe, Middle East and Africa Technical Support:**

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

